



REVERSE VOLTAGE – 100Volts

FORWARD CURRENT – 30 Amperes

LITE-ON SEMICONDUCTOR

MBRF30100CT(LS)

SCHOTTKY BARRIER RECTIFIER

FEATURES

- · Metal of silicon rectifier, majority carrier conduction
- Low forward voltage drop
- High efficiency
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
 Halogen and Antimony Free. "Green" Device (Note 3)

MECHANICAL DATA

- Package Material: Plastic material, UL flammability classification 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead Free Plating
- Polarity Indicator: As marked on the body
- Weight: 0.06 ounces, 1.70 grams
- Component in accordance to RoHS 2002/95/EC
- ESD Capability: HBM_8KV (JESD22-A114)
- Maximum mounting torque = 0.5N.m (5.1Kgf.cm)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

PARAMETER			SYMBOL	VALUE			UNIT
Device Marking Code			Note	MBRF30100CT			
Maximum Repetitive Peak Reverse Voltage			Vrrm	100			V
Average Rectified Output Cu	lF	30			А		
Peak Forward Surge Current 8.3ms Single Half Sine-Wave			IFSM	250			А
Storage Temperature Range	Tstg	-55 to +175			°C		
Operating Junction Temperature Range			TJ	-55 to +175			°C
PARAMETER	TEST CONDITIONS		SYMBOL	MIN.	TYP.	MAX.	UNIT
Breakdown Voltage	I _R =0.1mA	TJ=25°C	VB	100			V
Forward Voltage (Note 4)	I _F =15A	TJ=25°C TJ=125°C	VF		0.75 0.62	0.80 0.67	v
	IF=30A	TJ=25°C				0.93	
Leakage Current	V _R =100V	TJ=25°C TJ=125°C	IR		0.001 0.5	0.1 10	mA
THERMAL CHARACTERISTIC			SYMBOL	TYPICAL			UNIT
Typical Thermal Resistance_Junction to Case (Note 5)			R⊖JC	3.5			°C/W
Typical Thermal Resistance_Junction to Lead (Note 5)			R⊖JL	3.5			°C/W

Notes:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

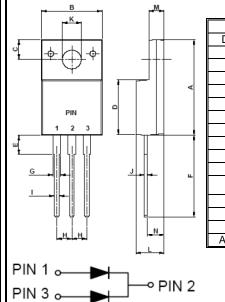
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

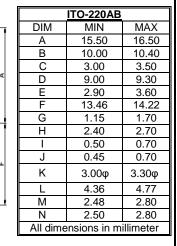
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony

compounds. 4. 300us Pulse Width, 2% Duty Cycle.

5. Thermal Resistance test performed in accordance with JESD-51. RoJL is measured at the PIN 2, RoJC is measured at the top centre of body.

ITO-220AB

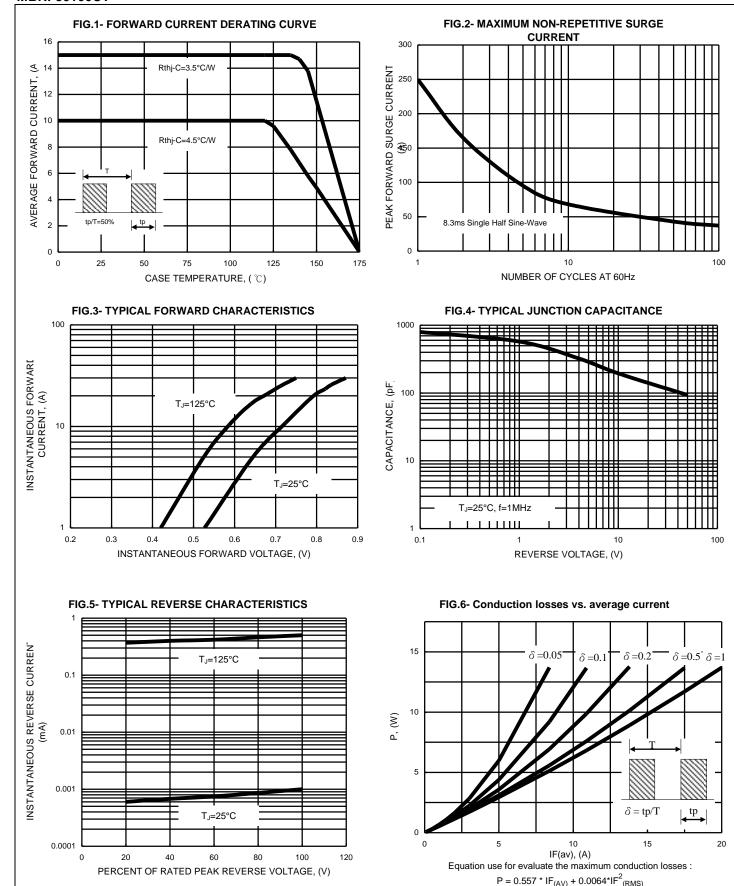






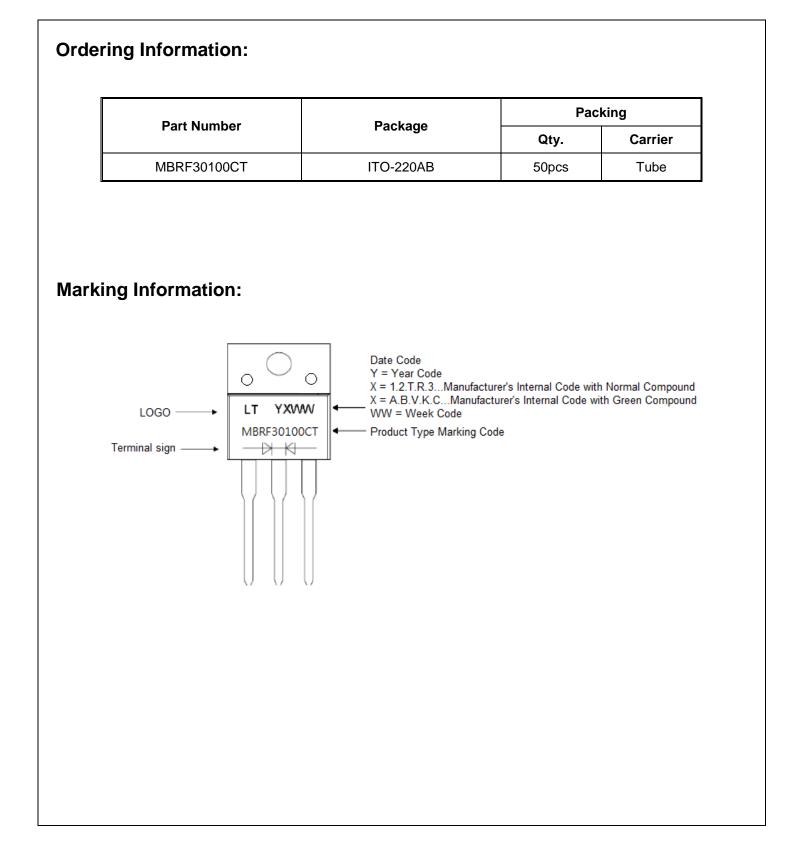
RATING AND CHARACTERISTIC CURVES MBRF30100CT

LITE-ON SEMICONDUCTOR





LITE-ON SEMICONDUCTOR





LITE-ON SEMICONDUCTOR

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